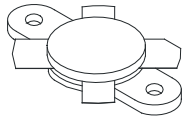
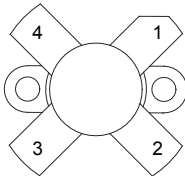


150 W – 50 V moisture resistant HF/VHF DMOS transistor



M174MR epoxy sealed

1. Drain
2. Source
3. Gate
4. Source



Features

- Gold metallization
- Excellent thermal stability
- Common source push-pull configuration
- $P_{OUT} = 150\text{ W}$ min. with 14 dB gain @ 175 MHz
- Thermally enhanced packing for lower junction temperatures
- G_{FS} and V_{GS} sort marked on unit
- Moisture resistant package specifically designed to operate in extreme environments

Description

The **SD2931-12MR** is a gold metallized N-channel MOS field-effect RF power transistor. Electrically identical to the standard SD2931 MOSFET, it is used for 50 V DC large signal applications up to 230 MHz.

The device is mechanically compatible with the SD2931 but offers better thermal capability (25% lower thermal resistance), representing the best-in-class in transistors for ISM applications, where reliability and ruggedness are critical factors.

The **SD2931-12MR** benefits from the latest generation of environmentally designed packing, ruggedized against cyclic high moisture operation and severe storage conditions.

| Product status | |
|-----------------|--------------|
| SD2931-12MR | |
| Product summary | |
| Order code | SD2931-12MR |
| Marking | SD2931-11MR |
| Package | M174 |
| Packing | Plastic tray |

1 Electrical data

1.1 Maximum ratings

 $T_{CASE} = 25\text{ °C}$
Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|---------------|--|-------------|------|
| $V_{(BR)DSS}$ | Drain source voltage | 125 | V |
| V_{DGR} | Drain-gate voltage ($R_{GS} = 1\text{ M}\Omega$) | 125 | V |
| V_{GS} | Gate-source voltage | ± 40 | V |
| I_D | Drain current | 20 | A |
| P_{DISS} | Power dissipation | 389 | W |
| T_J | Max. operating junction temperature | 200 | °C |
| T_{STG} | Storage temperature | -65 to +150 | °C |

1.2 Thermal data

Table 2. Thermal data

| Symbol | Parameter | Value | Unit |
|------------|-------------------------------------|-------|------|
| R_{thJC} | Junction-to-case thermal resistance | 0.45 | °C/W |

2 Electrical characteristics

 $T_{CASE} = 25\text{ }^{\circ}\text{C}$
Table 3. Static

| Symbol | Test conditions | Min. | Typ. | Max. | Unit |
|-------------------|---|-----------------|------|------|---------------|
| $V_{(BR)DSS}$ | $V_{GS} = 0\text{ V}$ $I_{DS} = 100\text{ mA}$ | 125 | | | V |
| I_{DSS} | $V_{GS} = 0\text{ V}$ $V_{DS} = 5\text{ V}$ | | | 20 | |
| | $V_{GS} = 0\text{ V}$ $V_{DS} = 50\text{ V}$ | | | 50 | μA |
| I_{GSS} | $V_{GS} = 20\text{ V}$ $V_{DS} = 0\text{ V}$ | | | 250 | nA |
| $V_{GS(Q)}^{(1)}$ | $V_{DS} = 10\text{ V}$ $I_D = 250\text{ mA}$ | See table below | | | V |
| $V_{DS(ON)}$ | $V_{GS} = 10\text{ V}$ $I_D = 10\text{ A}$ | | | 3.0 | V |
| $G_{FS}^{(1)}$ | $V_{DS} = 10\text{ V}$ $I_D = 5\text{ A}$ | See table below | | | mho |
| C_{ISS} | $V_{GS} = 0\text{ V}$ $V_{DS} = 50\text{ V}$ $f = 1\text{ MHz}$ | | 480 | | pF |
| C_{OSS} | $V_{GS} = 0\text{ V}$ $V_{DS} = 50\text{ V}$ $f = 1\text{ MHz}$ | | 190 | | pF |
| C_{RSS} | $V_{GS} = 0\text{ V}$ $V_{DS} = 50\text{ V}$ $f = 1\text{ MHz}$ | | 18 | | pF |

1. $V_{GS(Q)}$ and G_{FS} sorted with alpha/numeric code marked on unit.

Table 4. V_{GS} and G_{FS} sorts

| Code | V_{GS} | G_{FS} |
|------|-------------|-----------|
| I | 2.65 - 3.15 | 6.0 - 6.5 |
| J | 2.65 - 3.15 | 6.5 - 7.0 |
| K | 2.65 - 3.15 | 7.0 - 7.5 |

Table 5. Dynamic

| Symbol | Test conditions | Min. | Typ. | Max. | Unit |
|---------------|---|------|------|------|------|
| P_{OUT} | $V_{DD} = 50\text{ V}$ $I_{DQ} = 250\text{ mA}$ $f = 175\text{ MHz}$ | 150 | | | W |
| G_{PS} | $V_{DD} = 50\text{ V}$ $I_{DQ} = 250\text{ mA}$ $P_{OUT} = 150\text{ W}$ $f = 175\text{ MHz}$ | 14 | 15 | | dB |
| η_D | $V_{DD} = 50\text{ V}$ $I_{DQ} = 250\text{ mA}$ $P_{OUT} = 150\text{ W}$ $f = 175\text{ MHz}$ | 55 | 65 | | % |
| Load mismatch | $V_{DD} = 50\text{ V}$ $I_{DQ} = 250\text{ mA}$ $P_{OUT} = 150\text{ W}$ $f = 175\text{ MHz}$ all phase angles | 10:1 | | | VSWR |

3 Transient thermal impedance

Figure 3. Transient thermal impedance

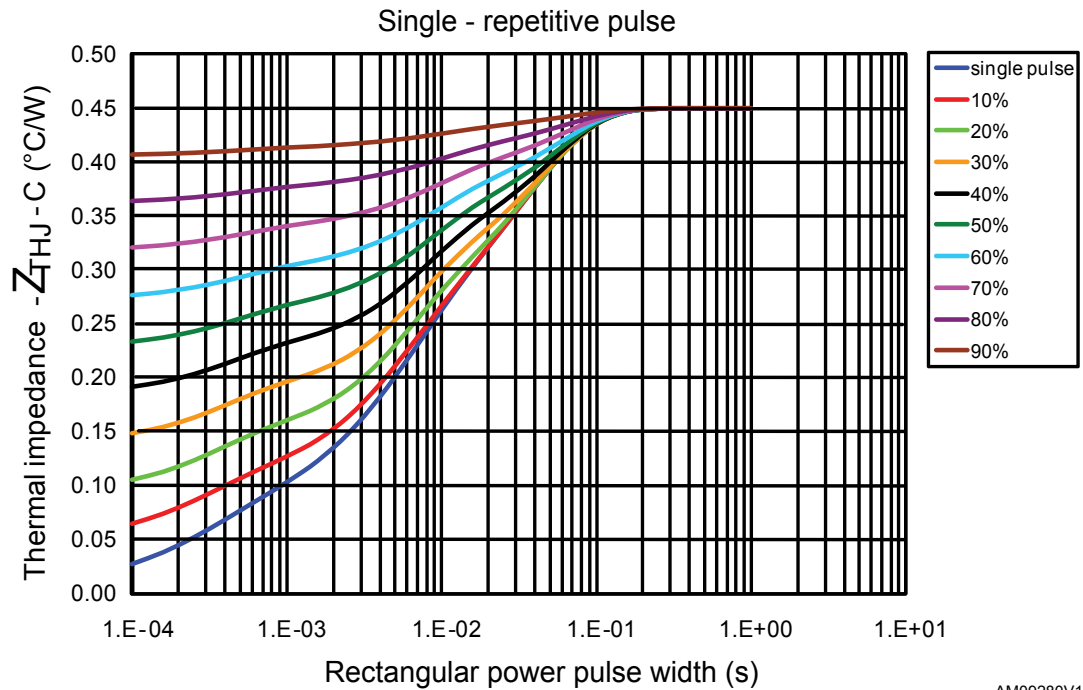
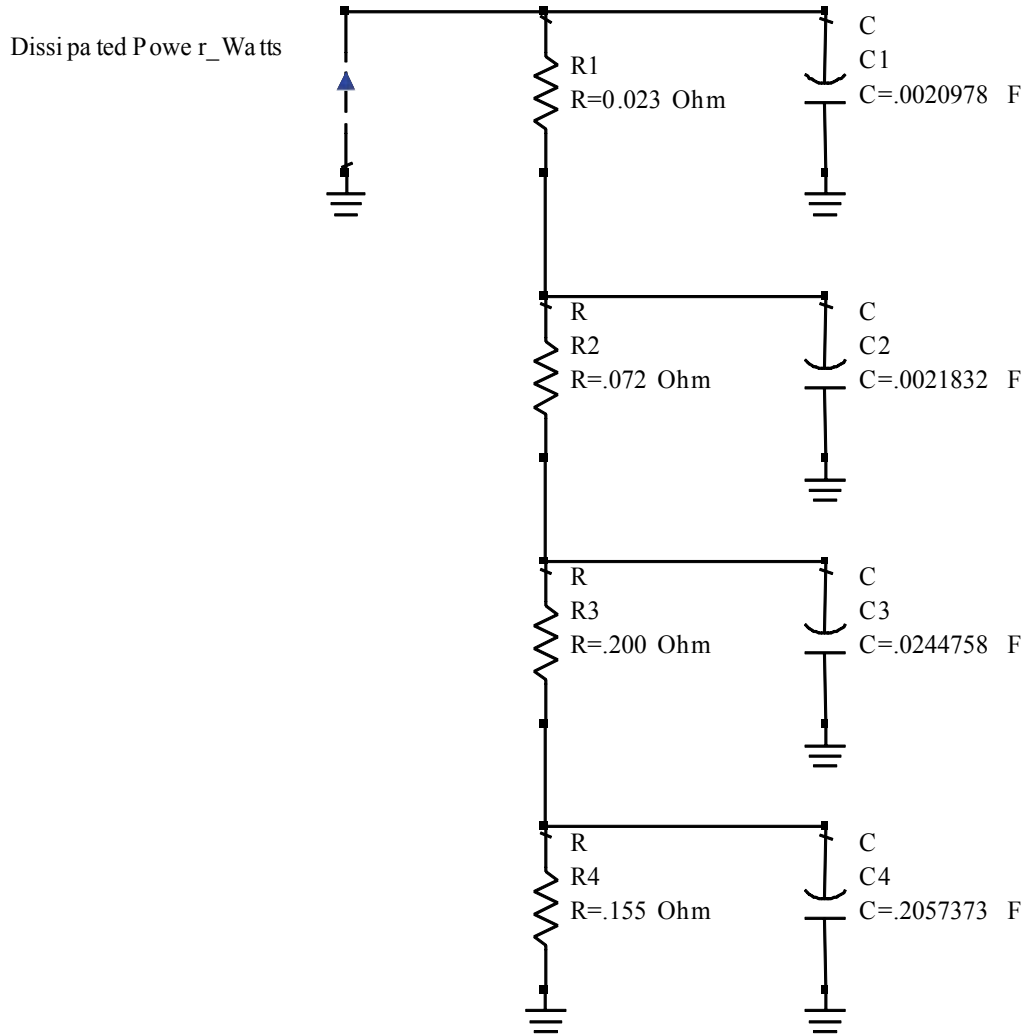
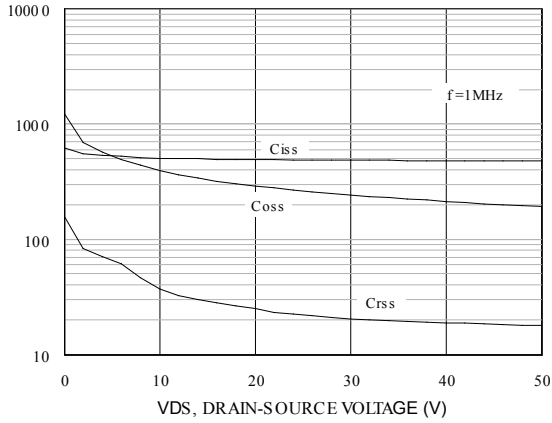
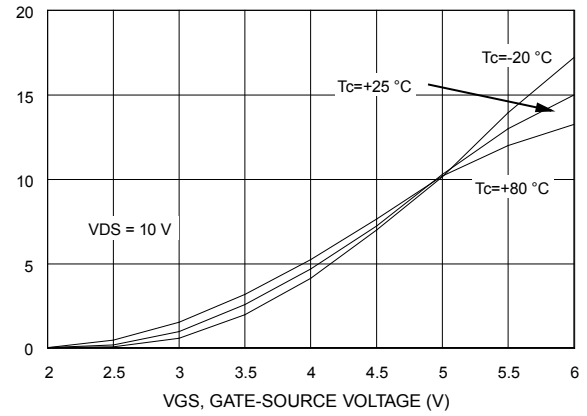
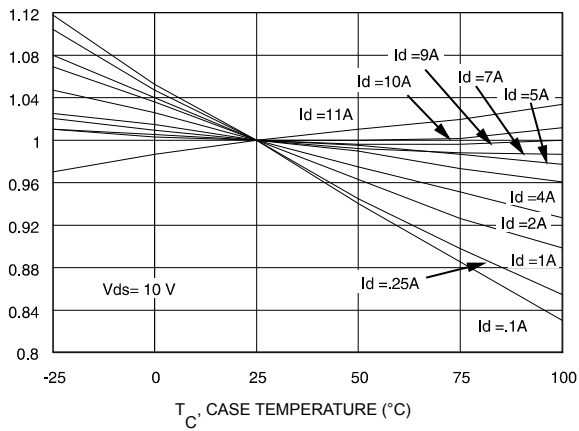
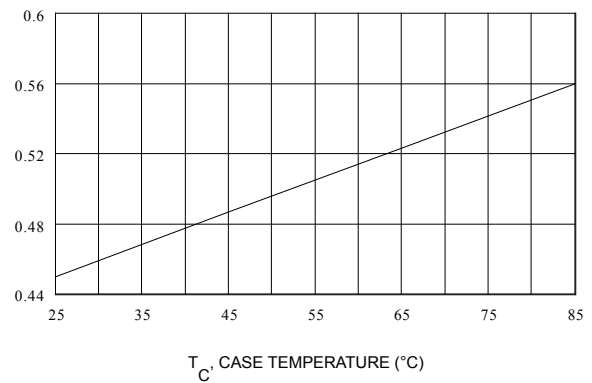
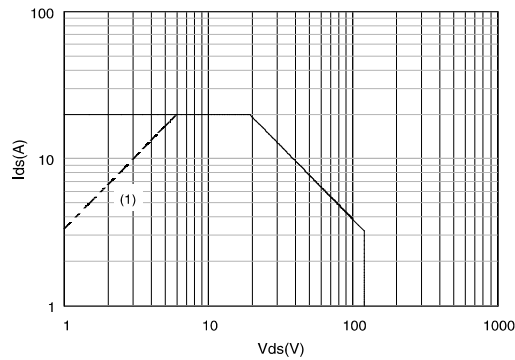


Figure 4. Transient thermal impedance model



AM09281V1

4 Typical performance

Figure 5. Capacitance vs. drain voltage

Figure 6. Drain current vs. gate voltage

Figure 7. Gate-source voltage vs. case temperature

Figure 8. Maximum thermal resistance vs. case temperature

Figure 9. Safe operating area


4.1 Typical performance (175 MHz)

Figure 10. Output power vs. input power

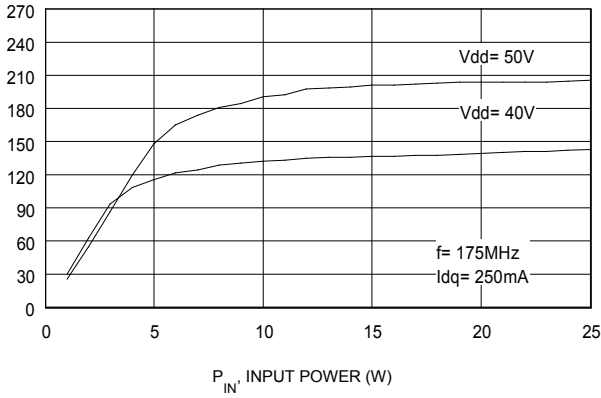


Figure 11. Output power vs. input power at different T_c

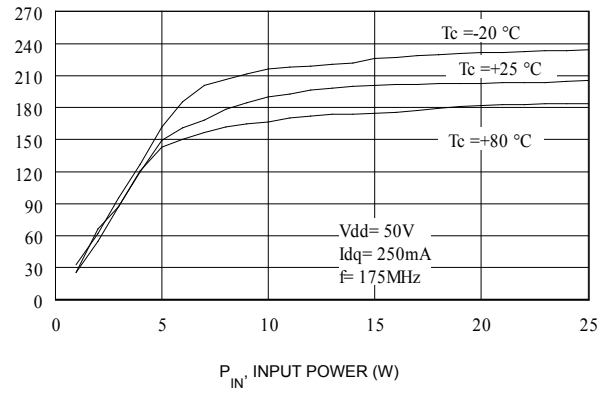


Figure 12. Power gain vs. output power

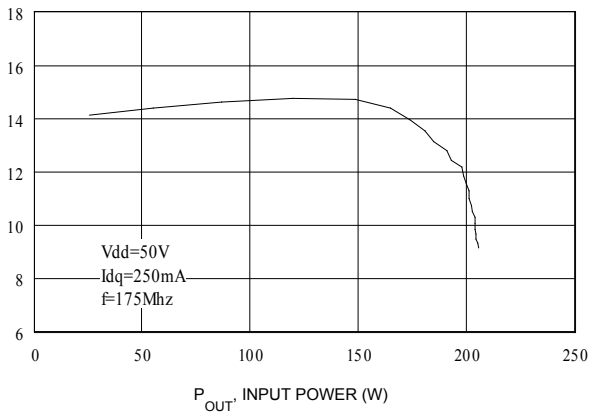


Figure 13. Efficiency vs. output power

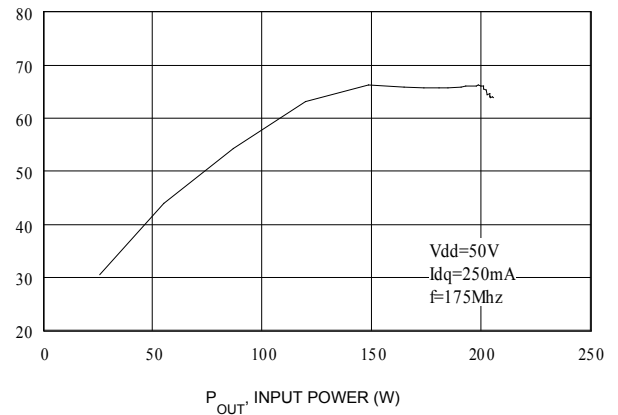


Figure 14. Output power vs. supply voltage

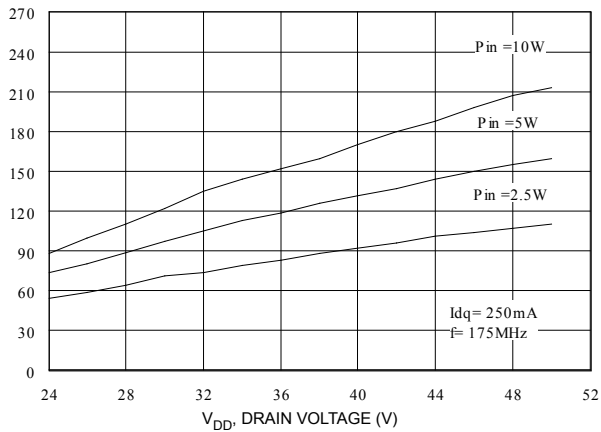
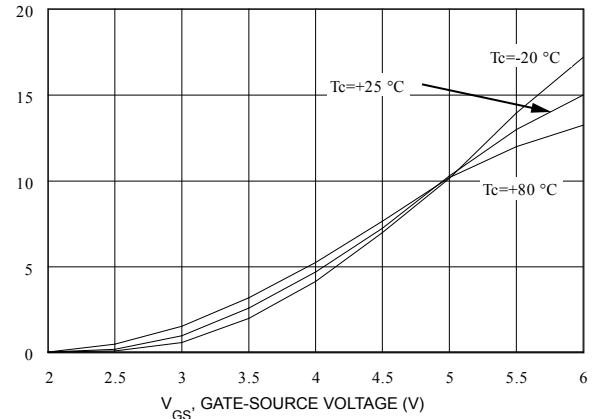


Figure 15. Drain current vs. gate-source voltage



4.1.1 Test circuit (175 MHz)

Figure 16. 175 MHz test circuit schematic (production test circuit)

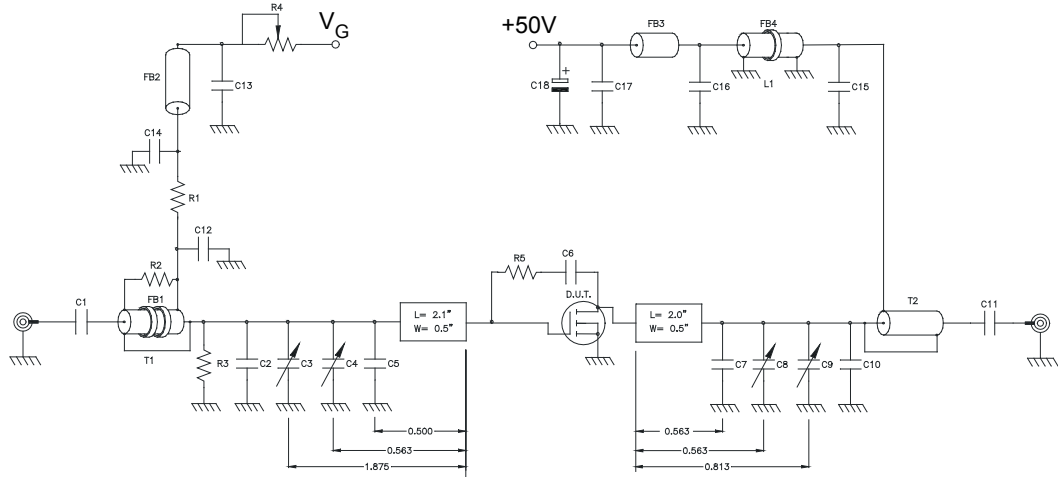


Table 6. 175 MHz test circuit part list

| Component | Description |
|--------------------|--|
| T1 | 4:1 transformer, 25 Ω flexible coax .090 OD 6" long |
| T2 | 1:4 transformer, 25 Ω semi-rigid coax .141 OD 6" long |
| FB1 | Toroid X 2, 0.5" OD .312" ID 850 μ 2 turns |
| FB2, FB3 | VK200 |
| FB4 | Shield bead, 1" OD 0.5" ID 850 μ 3 turns |
| L1 | 1/4 wave choke, 50 Ω semi-rigid coax .141 OD 12" long |
| PCB | 0.62" woven fiberglass, 1 oz. copper, 2 sides, $\epsilon_r = 2.55$ |
| R1, R3 | 470 Ω 1 W chip resistor |
| R2 | 360 Ω 1/2 W resistor |
| R4 | 20 k Ω 10 turn potentiometer |
| R5 | 560 Ω 1 W resistor |
| C1, C11 | 470 pF ATC chip cap |
| C2 | 43 pF ATC chip cap |
| C3, C8, C9 | Arco 404, 12-65 pF |
| C4 | Arco 423, 16-100 pF |
| C5 | 120 pF ATC chip cap |
| C6 | 0.01 μ F ATC chip cap |
| C7 | 30 pF ATC chip cap |
| C10 | 91 pF ATC chip cap |
| C12, C15 | 1200 pF ATC chip cap |
| C13, C14, C16, C17 | 0.01 μ F / 500 V chip cap |
| C18 | 10 μ F 63 V electrolytic capacitor |

Figure 17. 175 MHz test circuit photomaster

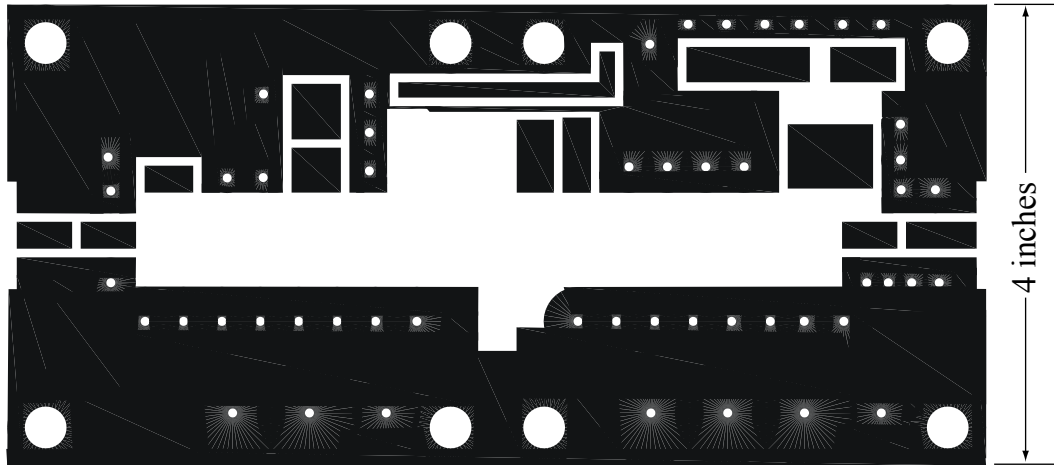
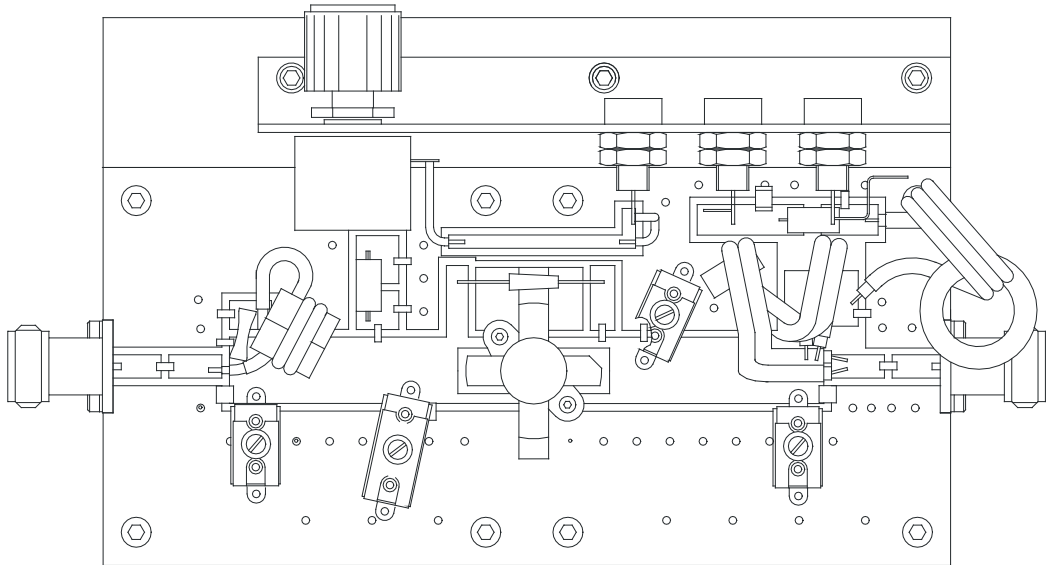


Figure 18. 175 MHz test circuit



4.2 Typical performance (30 MHz)

Figure 19. Output power vs. input power

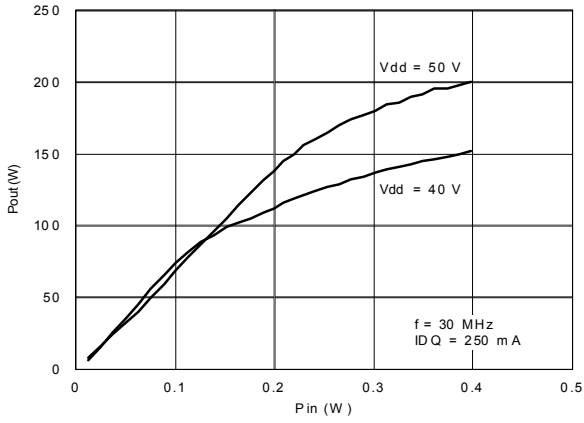


Figure 20. Power gain vs. output power

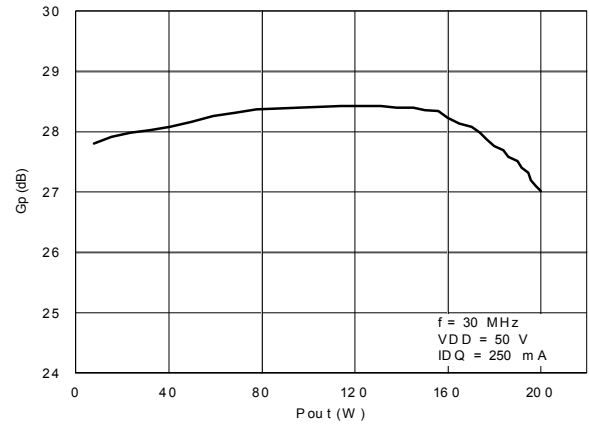


Figure 21. Efficiency vs. output power

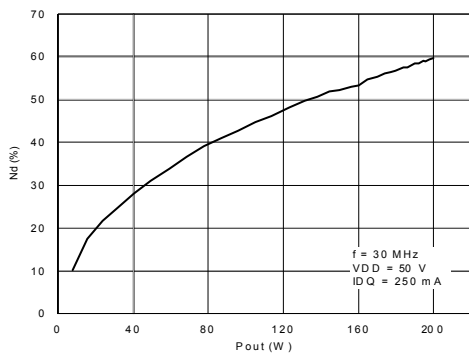


Figure 22. Output power vs. supply voltage

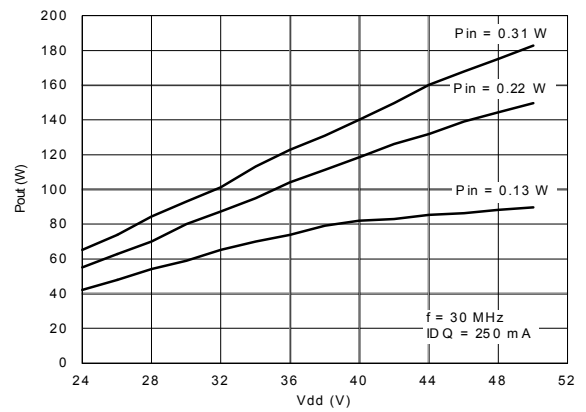
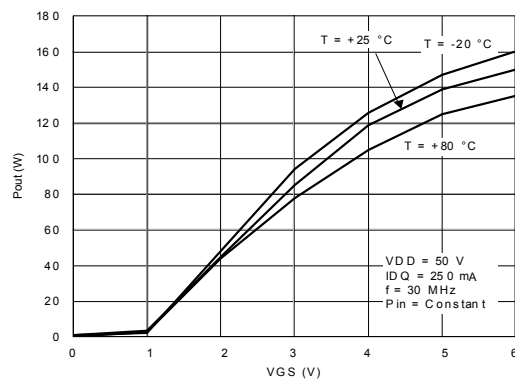


Figure 23. Output power vs. gate-source voltage



4.2.1 Test circuit (30 MHz)

Figure 24. 30 MHz test circuit schematic (production test circuit)

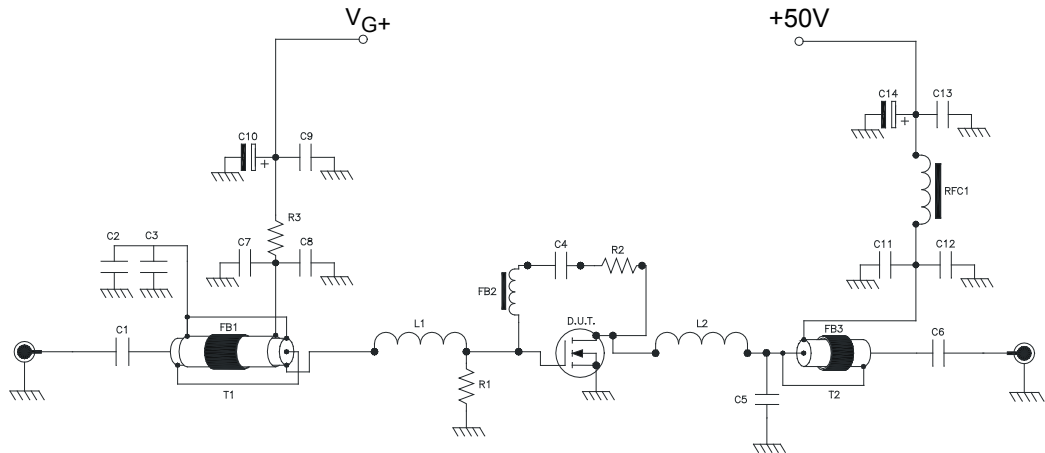


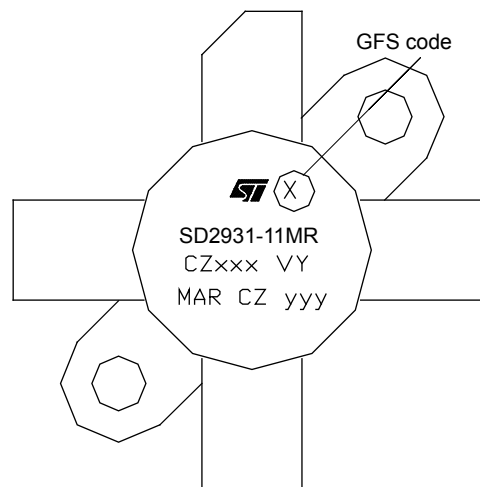
Table 7. 30 MHz test circuit part list

| Component | Description |
|---------------------------------------|--|
| T1 | 9:1 transformer, 25 Ω flexible coax with extra shield .090 OD 15" long |
| T2 | 1:4 transformer, 50 Ω flexible coax .225 OD 15" long |
| FB1 | Toroid 1.7" OD .30" ID 220 μ 4 turns |
| FB2 | Surface mount EMI shield bead |
| FB3 | Toroid 1.7" OD .300" ID 220 μ 3 turns |
| RFC1 | Toroid 0.5" OD 0.30" ID 125 μ 4 turns 12 awg wire |
| PCB | 0.62" woven fiberglass, 1 oz. copper, 2 sides, $\epsilon_r = 2.55$ |
| R1, R3 | 1 kohm 1 W chip resistor |
| R2 | 680 ohm 3 W wirewound resistor |
| C1, C4, C6, C7, C8, C9, C11, C12, C13 | 0.1 μF ATC chip cap |
| C2, C3 | 750 pF ATC chip cap |
| C5 | 470 pF ATC chip cap |
| C10 | 10 μF 63 V electrolytic capacitor |
| C14 | 100 μF 63 V electrolytic capacitor |

5 Marking, packing and shipping specifications

Table 8. Packing and shipping specifications

| Order code | Packing | Pieces per tray | Dry pack humidity | V _{GS} and G _{FS} code | Lot code |
|-------------|--------------|-----------------|-------------------|--|-----------|
| SD2931-12MR | Plastic tray | 25 | < 10% | Not mixed | Not mixed |

Figure 25. SD2931-12MR marking layout

Table 9. Marking specifications

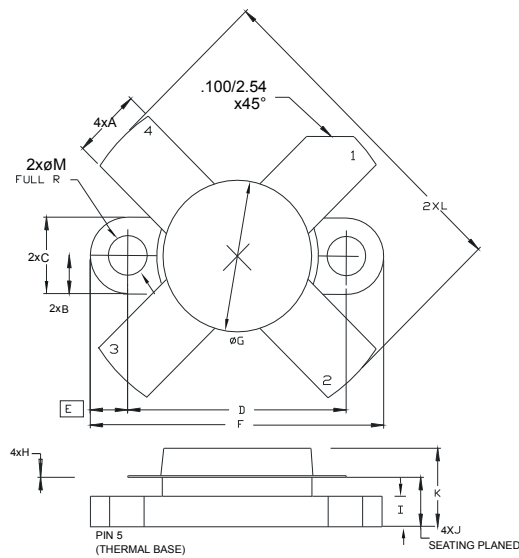
| Symbol | Description |
|--------|--|
| X | V _{GS} and G _{FS} sort |
| CZ | Assembly plant |
| xxx | Last 3 digits of diffusion lot |
| VY | Diffusion plant |
| MAR | Country of origin |
| CZ | Test and finishing plant |
| y | Assembly year |
| yy | Assembly week |

6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

6.1 M174MR package information

Figure 26. M174MR package outline



8410504 rev. A

Table 10. M174 package mechanical data

| Dim. | mm | | |
|------|-------|------|-------|
| | Min. | Typ. | Max. |
| A | 5.56 | | 5.584 |
| B | | 3.18 | |
| C | 6.22 | | 6.48 |
| D | 18.28 | | 18.54 |
| E | | 3.18 | |
| F | 24.64 | | 24.89 |
| G | 12.07 | | 12.83 |
| H | 0.08 | | 0.18 |
| I | 2.11 | | 3.00 |
| J | 3.81 | | 4.45 |
| K | | | 8.00 |
| L | 25.53 | | 26.67 |
| M | 3.05 | | 3.30 |

Revision history

Table 11. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 20-Feb-2013 | 1 | Initial release |
| 10-Sep-2013 | 2 | Document promoted from preliminary data to full datasheet. Formatting and minor text changes. |
| 11-Nov-2016 | 3 | Updated <i>Table 2: "Absolute maximum ratings"</i> . |
| 07-Feb-2018 | 4 | Updated marking in cover page and Figure 25. SD2931-12MR marking layout . Minor text changes. |

Contents

| | | |
|----------|---|-----------|
| 1 | Electrical data | 2 |
| 1.1 | Maximum ratings | 2 |
| 1.2 | Thermal data | 2 |
| 2 | Electrical characteristics | 3 |
| 3 | Transient thermal impedance | 4 |
| 4 | Typical performance | 6 |
| 4.1 | Typical performance (175 MHz) | 6 |
| 4.1.1 | Test circuit (175 MHz) | 7 |
| 4.2 | Typical performance (30 MHz) | 9 |
| 4.2.1 | Test circuit (30 MHz) | 10 |
| 5 | Marking, packing and shipping specifications | 12 |
| 6 | Package information | 13 |
| 6.1 | M174MR package information | 13 |
| | Revision history | 14 |
| | Contents | 15 |
| | Disclaimer | 16 |

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST’s terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers’ products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2018 STMicroelectronics – All rights reserved



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.